SN74ALVC16600 18-BIT UNIVERSAL BUS TRANSCEIVER WITH 3-STATE OUTPUTS

DGG OR DL PACKAGE (TOP VIEW)

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- Member of the Texas Instruments Widebus™ Family
- UBT[™] (Universal Bus Transceiver)
 Combines D-Type Latches and D-Type
 Flip-Flops for Operation in Transparent,
 Latched, Clocked, or Clock-Enabled Mode
- EPIC[™] (Enhanced-Performance Implanted CMOS) Submicron Process
- Designed to Facilitate Incident-Wave Switching for Line Impedances of 50 Ω or Greater
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 2 V at V_{CC} = 3.3 V, T_A = 25°C
- Bus-Hold On Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages

description

This 18-bit universal bus transceiver is designed for 2.7-V to 3.6-V V_{CC} operation.

The SN74ALVC16600 combines D-type latches and D-type flip-flops to allow data flow in transparent, latched, and clocked modes.

Data flow in each direction is controlled by output-enable (OEAB and OEBA), latch-enable (LEAB and LEBA), and clock (CLKAB and

CLKBA) inputs. The clock can be controlled by the clock-enable (CLKENAB and CLKENBA) inputs. For A-to-B data flow, the device operates in the transparent mode when LEAB is high. When LEAB is low, the A data is latched if CLKAB is held at a high or low logic level. If LEAB is low, the A-bus data is stored in the latch/flip-flop on the high-to-low transition of CLKAB. Output enable OEAB is active low. When OEAB is low, the outputs are active. When OEAB is high, the outputs are in the high-impedance state.

Data flow for B to A is similar to that of A to B but uses OEBA, LEBA, CLKBA, and CLKENBA.

The SN74ALVC16600 is available in Ti's shrink small-outline (DL) and thin shrink small-outline (DGG) packages, which provide twice the I/O pin count and functionality of standard small-outline packages in the same printed-circuit-board area.

The SN74ALVC16600 is characterized for operation from –40°C to 85°C.

OEAB 56 CLKENAB LEAB [2 55 CLKAB A1 🛭 54 ¶ B1 3 53 GND GND 4 52 B2 A2 🛮 5 51 B3 A3 🛛 6 50 VCC $V_{CC} \sqcup$ A4 🛮 8 49 ¶ B4 A5 9 48 B5 47 B6 A6 📙 10 46 GND GND [11 45 🛮 B7 A7 12 A8 [] 44 B8 13 А9 П 14 43 B9 42 B10 A10 1 15 A11 41 B11 16 A12 17 40 **∏** B12 GND **1** 18 39 | GND A13 19 38 B13 37 **∏** B14 A14 20 A15 21 36 **∏** B15 V_{CC} 🛮 22 35 V_{CC} A16 23 34 **□** B16 A17 ∏ 24 33**∏** B17 GND ☐ 25 32 | GND А18 Г 31 B18 26 OEBA [27 30 CLKBA

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29 CLKENBA

LEBA []

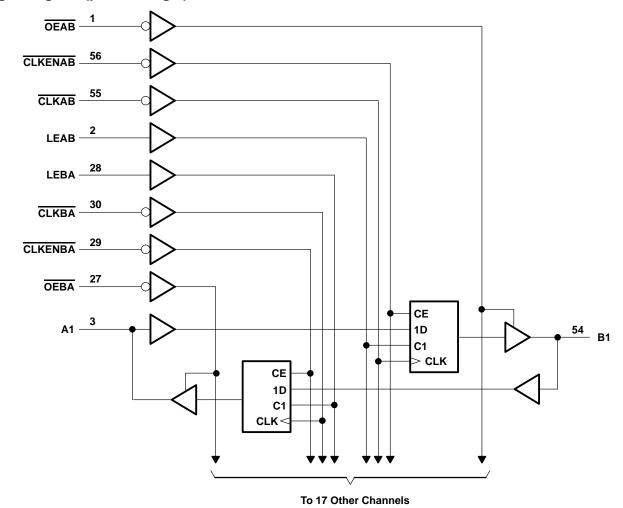
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FUNCTION TABLE†

INPUTS				OUTPUT	
CLKENAB	OEAB	LEAB	CLKAB	Α	В
Х	Н	Х	Х	Χ	Z
Х	L	Н	Χ	L	L
Х	L	Н	Χ	Н	Н
Н	L	L	Χ	Χ	в ₀ ‡
Н	L	L	Χ	Χ	в ₀ ‡ в ₀ ‡
L	L	L	\downarrow	L	L
L	L	L	\downarrow	Н	Н
L	L	L	Н	Χ	в ₀ ‡
L	L	L	L	Χ	в ₀ ‡ в ₀ §

[†] A-to-B data flow is shown: B-to-A flow is similar but uses $\overline{\text{OEBA}}$, LEBA, $\overline{\text{CLKBA}}$, and $\overline{\text{CLKENBA}}$.

logic diagram (positive logic)



TEXAS INSTRUMENTS

[‡] Output level before the indicated steady-state input conditions were established.

[§] Output level before the indicated steady-state input conditions were established, provided that CLKAB was low before LEAB went low.

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 4.6 V
Input voltage range, V _I (except I/O ports) (see Note 1)	
Input voltage range, V _I (I/O ports) (see Notes 1 and 2)	\dots -0.5 V to V _{CC} + 0.5 V
Output voltage range, VO (see Notes 1 and 2)	\dots -0.5 V to V _{CC} + 0.5 V
Input clamp current, I_{IK} ($V_I < 0$)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$ or $V_O > V_{CC}$)	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	±50 mA
Continuous current through V _{CC} or GND	±100 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 3): DC	GG package 1 W
DL	package 1.4 W
Storage temperature range	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

- 2. This value is limited to 4.6 V maximum.
- 3. The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils. For more information, refer to the *Package Thermal Considerations* application note.

recommended operating conditions

			MIN	MAX	UNIT	
VCC	Supply voltage		2.7	3.6	V	
VIH	High-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2		V	
V _{IL}	Low-level input voltage	$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		0.8	V	
٧ _I	Input voltage		0	Vcc	V	
۷o	Output voltage		0	VCC	V	
ЮН	High-level output current	V _{CC} = 2.7 V		-12	mA	
		V _{CC} = 3 V		-24		
loL	Low-level output current	V _{CC} = 2.7 V		12	mA	
	Low-level output current	V _{CC} = 3 V		24		
Δt/Δν	Input transition rise or fall rate		0	10	ns/V	
TA	Operating free-air temperature		-40	85	°C	

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PA	RAMETER	TEST CONDITIONS	v _{cc} †	MIN	MAX	UNIT	
		$I_{OH} = -100 \mu\text{A}$	MIN to MAX	V _{CC} -0	.2		
W	12 mA	2.7 V	2.2		V		
VOH		$I_{OH} = -12 \text{ mA}$	3 V	2.4			
		$I_{OH} = -24 \text{ mA}$	3 V	2			
VOL		I _{OL} = 100 μA	MIN to MAX		0.2		
		I _{OL} = 12 mA	2.7 V		0.4	V	
		I _{OL} = 24 mA	3 V		0.55		
Ц		V _I = V _{CC} or GND	3.6 V		±5	μΑ	
I _{I(hold)} Da	Data I/Oa	V _I = 0.8 V	2.1/	75		μΑ	
	Data I/Os	V _I = 2 V	3 V	-75			
loz‡		$V_O = V_{CC}$ or GND	3.6 V		±10	μΑ	
Icc		$V_I = V_{CC}$ or GND, $I_O = 0$	3.6 V		40	μΑ	
ΔICC		V_{CC} = 3 V to 3.6 V, One input at V_{CC} – 0.6 V, Other inputs at V_{CC} or GND			750	μΑ	
Ci	Control inputs	$V_I = V_{CC}$ or GND	3.3 V			pF	
C _{io}	A or B ports	$V_O = V_{CC}$ or GND	3.3 V			pF	

[†] For conditions shown as MIN or MAX, use the appropriate values under recommended operating conditions.

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